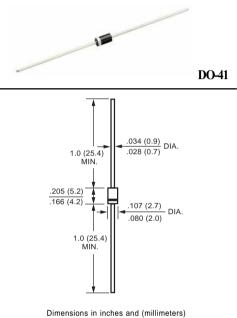


HIGH VOLTAGE SILICON RECTIFIER

VOLTAGE RANGE 1200 to 2000 Volts CURRENT 0.2 to 0.5 Ampere

FEATURES * Low cost * Low cost * Low leakage * Low forward voltage drop * High current capability MECHANICAL DATA * Case: Molded plastic * Epoxy: Device has UL flammability classification 94V-O * Lead: MIL-STD-202E method 208C guaranteed * Mounting position: Any * Weight: 0.35 gram MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load.



MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

For capacitive load, derate current by 20%.

RATINGS	SYMBOL	R1200	R1500	R1800	R2000	UNITS
Maximum Recurrent Peak Reverse Voltage	Vrrm	1200	1500	1800	2000	Volts
Maximum RMS Volts	Vrms	840	1050	1260	1400	Volts
Maximum DC Blocking Voltage	VDC	1200	1500	1800	2000	Volts
Maximum Average Forward Rectified Current at TA = 50°C	lo	500 2			200	mAmps
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	IFSM		Amps			
Typical Junction Capacitance (Note)	CJ		pF			
Operating and Storage Temperature Range	TJ, TSTG		° C			

ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

CHARACTERISTICS		SYMBOL	R1200	R1500	R1800	R2000	UNITS
Maximum Instantaneous Forward Voltage at 0.5A/0.2A DC		VF	2.0			3.0	Volts
Maximum DC Reverse Current	@TA = 25°C		5.0				uAmps
at Rated DC Blocking Voltage	@TA =100°C	IR	50				
Maximum Full Load Reverse Current Average, Full Cycle .375", (9.5mm) lead length at $TL = 75^{\circ}C$			30				uAmps

NOTES : Measured at 1 MHz and applied reverse voltage of 4.0 volts.

RATING AND CHARACTERISTIC CURVES (R1200 THRU R2000)

